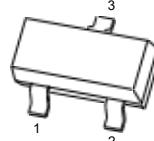
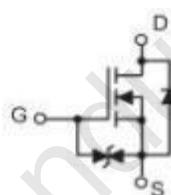


<b>V<sub>(BR)DSS</sub></b>	<b>R<sub>D(on)MAX</sub></b>	<b>I<sub>D</sub></b>
50V	3.5Ω@ 10V	0.22A
	6.0Ω@4.5V	

**SOT-23**

 1.GATE  
 2.SOURCE  
 3.DRAIN

**Equivalent Circuit**

**Features**

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) ESD protected 2KV HBM

**Applications**

Interfacing, switching (50V, 100mA)

**ORDERING INFORMATION**

Type No.	Marking	Package Code
<u>BSS138</u>	<u>SS/J1</u>	<u>SOT-23</u>

**Absolute Maximum Ratings**
T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage	50	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current – Continuous (Note 1)	0.22	A
	– Pulsed	0.88	
P <sub>D</sub>	Maximum Power Dissipation (Note 1)	0.36	W
	Derate Above 25°C	2.8	mW/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering Purposes 1/16" from Case for 10 Seconds	300	°C

**Thermal Characteristics**

R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient (Note 1)	350	°C/W
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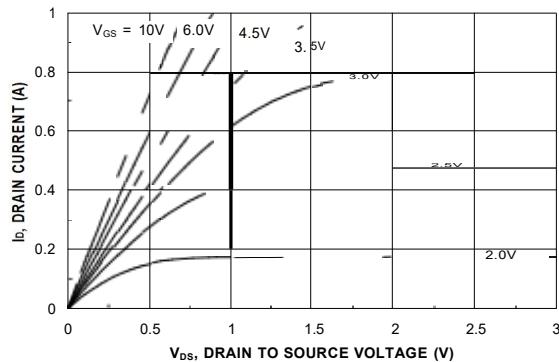
**Package Marking and Ordering Information**

Device Marking	Device	Reel Size	Tape width	Quantity
SS	BSS138	7"	8mm	3000 units

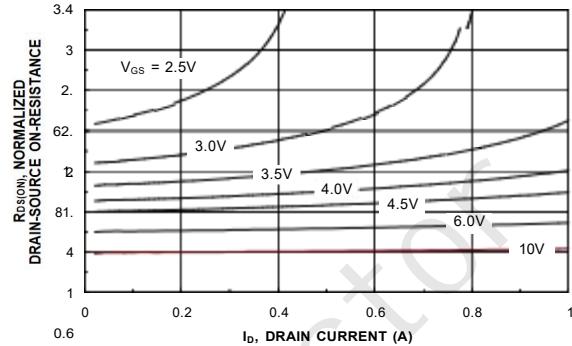
$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
<b>Off Characteristics</b>						
$\text{BV}_{\text{DSS}}$	Drain–Source Breakdown Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_D = 250 \text{ }\mu\text{A}$	50			V
$\frac{\Delta \text{BV}_{\text{DSS}}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \text{ }\mu\text{A}$ , Referenced to $25^\circ\text{C}$		72		$\text{mV}/^\circ\text{C}$
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 50 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$			0.5	$\text{mA}$
		$V_{\text{DS}} = 30 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$			100	nA
$I_{\text{GSS}}$	Gate–Body Leakage.	$V_{\text{GS}} = \pm 20 \text{ V}$ , $V_{\text{DS}} = 0 \text{ V}$			$\pm 100$	nA
<b>On Characteristics</b> (Note 2)						
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}} = V_{\text{GS}}$ , $I_D = 1 \text{ mA}$	0.8	1.3	1.6	V
$\frac{\Delta V_{\text{GS}(\text{th})}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 1 \text{ mA}$ , Referenced to $25^\circ\text{C}$		-2		$\text{mV}/^\circ\text{C}$
$R_{\text{DS}(\text{on})}$	Static Drain–Source On–Resistance	$V_{\text{GS}} = 10 \text{ V}$ , $I_D = 0.22 \text{ A}$			3.5	$\Omega$
		$V_{\text{GS}} = 4.5 \text{ V}$ , $I_D = 0.22 \text{ A}$			6.0	
$I_{\text{D(on)}}$	On–State Drain Current	$V_{\text{GS}} = 10 \text{ V}$ , $V_{\text{DS}} = 5 \text{ V}$	0.2			A
$g_{\text{FS}}$	Forward Transconductance	$V_{\text{DS}} = 10 \text{ V}$ , $I_D = 0.22 \text{ A}$	0.12			S
<b>Dynamic Characteristics</b>						
$C_{\text{iss}}$	Input Capacitance	$V_{\text{DS}} = 25 \text{ V}$ , $V_{\text{GS}} = 0 \text{ V}$ , $f = 1.0 \text{ MHz}$		27		pF
$C_{\text{oss}}$	Output Capacitance			13		pF
$C_{\text{rss}}$	Reverse Transfer Capacitance			6		pF
$R_G$	Gate Resistance	$V_{\text{GS}} = 15 \text{ mV}$ , $f = 1.0 \text{ MHz}$		9		$\Omega$
<b>Switching Characteristics</b> (Note 2)						
$t_{\text{d(on)}}$	Turn–On Delay Time	$V_{\text{DD}} = 30 \text{ V}$ , $I_D = 0.29 \text{ A}$ , $V_{\text{GS}} = 10 \text{ V}$ , $R_{\text{GEN}} = 6 \Omega$		2.5	5	ns
$t_r$	Turn–On Rise Time			9	18	ns
$t_{\text{d(off)}}$	Turn–Off Delay Time			20	36	ns
$t_f$	Turn–Off Fall Time			7	14	ns
$Q_g$	Total Gate Charge	$V_{\text{DS}} = 25 \text{ V}$ , $I_D = 0.22 \text{ A}$ , $V_{\text{GS}} = 10 \text{ V}$		1.7	2.4	nC
$Q_{\text{gs}}$	Gate–Source Charge			0.1		nC
$Q_{\text{gd}}$	Gate–Drain Charge			0.4		nC
<b>Drain–Source Diode Characteristics and Maximum Ratings</b>						
$I_s$	Maximum Continuous Drain–Source Diode Forward Current				0.22	A
$V_{\text{SD}}$	Drain–Source Diode Forward Voltage	$V_{\text{GS}} = 0 \text{ V}$ , $I_s = 0.44 \text{ A}$ (Note 2)		0.8	1.4	V

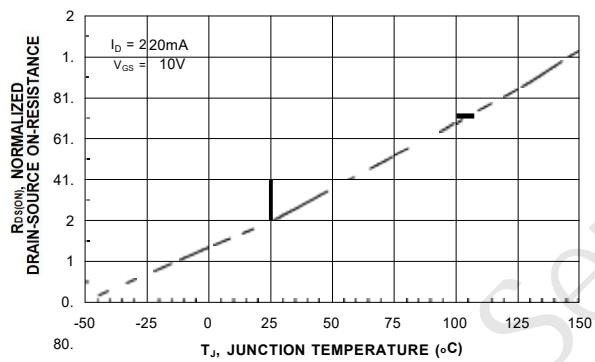
## Typical Characteristics



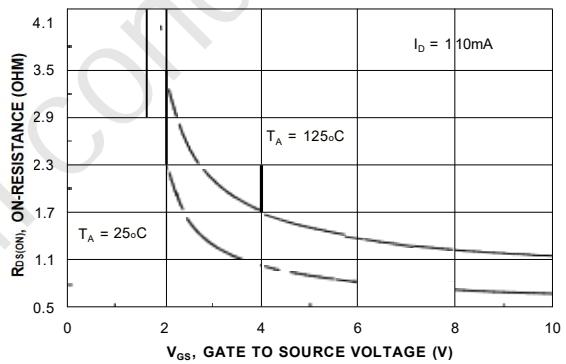
**Figure 1. On-Region Characteristics.**



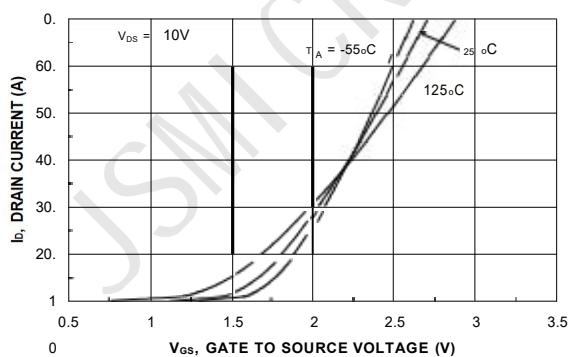
**Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.**



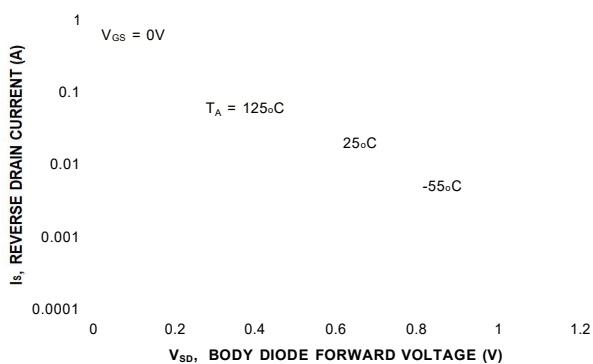
**Figure 3. On-Resistance Variation with Temperature.**



**Figure 4. On-Resistance Variation with Gate-to-Source Voltage.**



**Figure 5. Transfer Characteristics.**



**Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.**

### Typical Characteristics

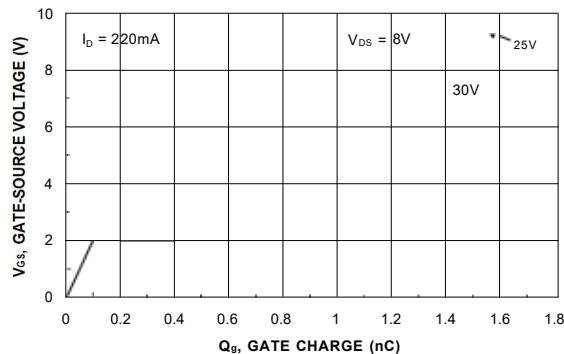


Figure 7. Gate Charge Characteristics.

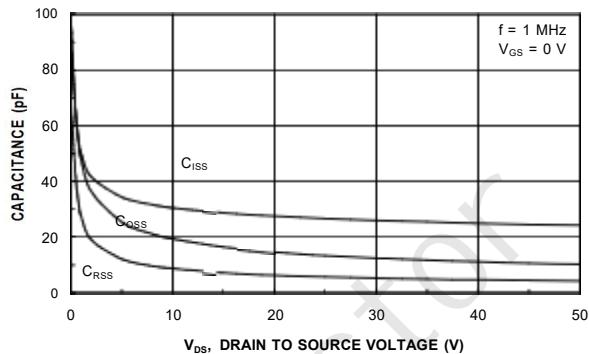


Figure 8. Capacitance Characteristics.

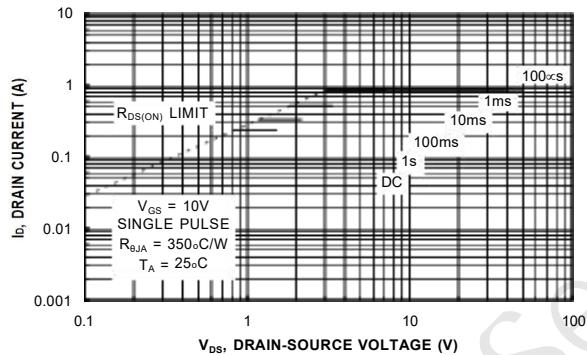


Figure 9. Maximum Safe Operating Area.

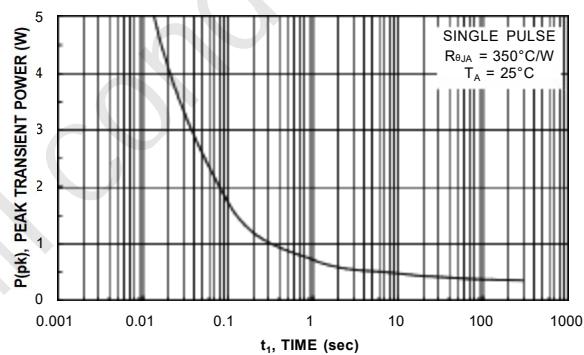


Figure 10. Single Pulse Maximum Power Dissipation.

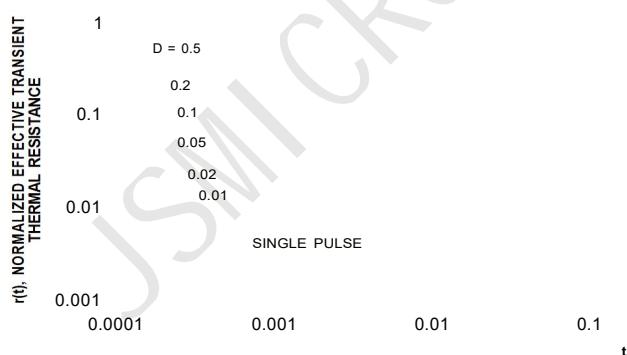
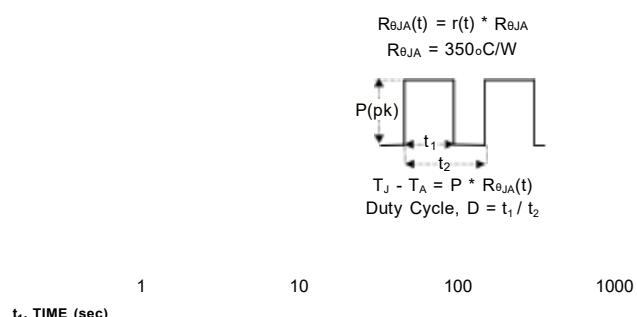


Figure 11. Transient Thermal Response Curve.

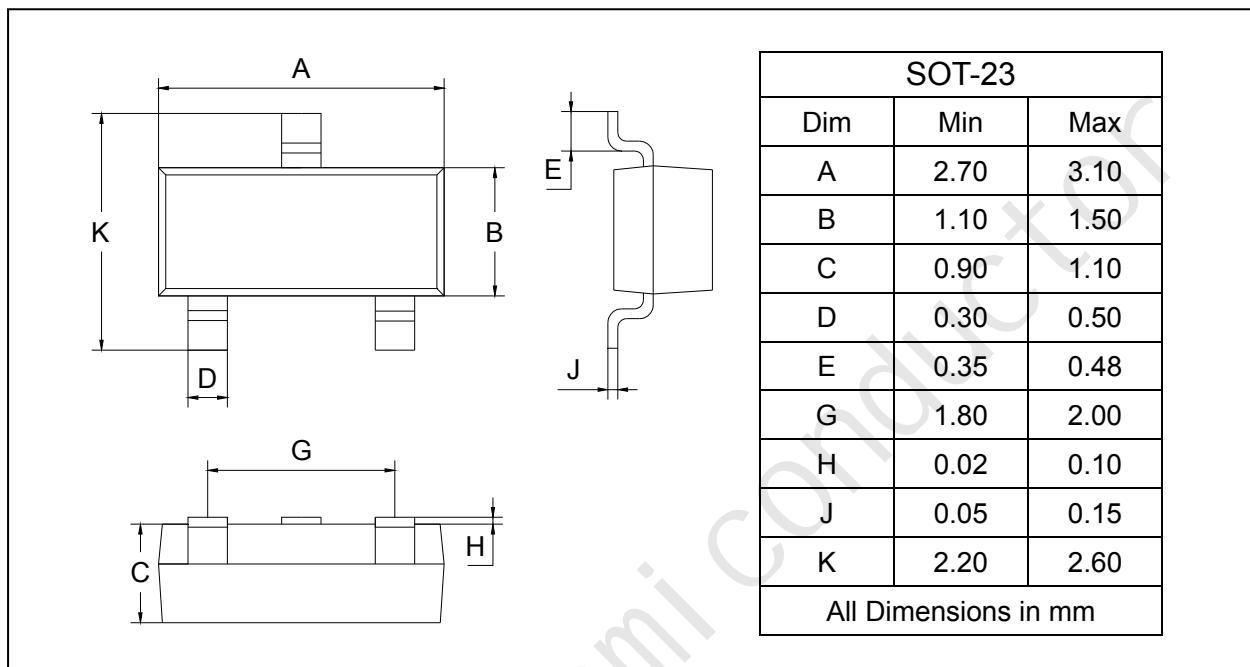
Thermal characterization performed using the conditions described in Note 1a.  
 Transient thermal response will change depending on the circuit board design.



## PACKAGE OUTLINE

Plastic surface mounted package

SOT-23

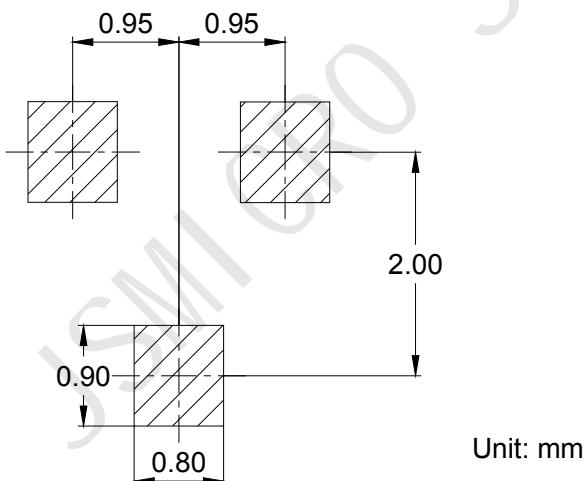


The diagram illustrates the physical dimensions of the SOT-23 package. The top view shows the overall footprint with dimensions A (width), B (height), C (lead thickness), D (lead spacing), E (lead height), G (lead pitch), H (lead width), and K (total height). The side view provides a detailed look at the lead profile with dimensions J and E.

SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	0.90	1.10
D	0.30	0.50
E	0.35	0.48
G	1.80	2.00
H	0.02	0.10
J	0.05	0.15
K	2.20	2.60

All Dimensions in mm

## SOLDERING FOOTPRINT



## PACKAGE INFORMATION

Device	Package	Shipping
BSS138	SOT-23	3000 pcs / Tape & Reel

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